

1A, 30V - 60V Surface Mount Schottky Barrier Rectifier

FEATURES

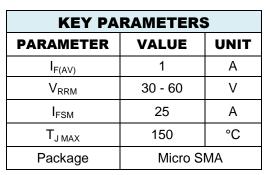
- AEC-Q101 qualified
- Very low profile typical height of 0.68mm
- Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

Δ	D	D	 C	Δ'	TI	n	N	S
_				_		u	14	J

- Converter
- Free wheeling
- LED lighting
- Adapters

MECHANICAL DATA

- Case: Micro SMA
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.006 g (approximately)











Micro SMA

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
PARAMETER	SYMBOL	SS13M	SS14M	SS16M	UNIT		
Marking code on the device		Α	В	С			
Repetitive peak reverse voltage	V_{RRM}	30	40	60	V		
Forward current	I _{F(AV)}	1		Α			
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	25		А			
Junction temperature	T_J	- 55 to +150		°C			
Storage temperature	T _{STG}	- 55 to +150		°C			

1 Version: N1810



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP.	UNIT			
Junction-to-lead Thermal Resistance	R _{OJL}	30	°C/W			
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	125	°C/W			
Junction-to-case thermal resistance	R _{eJC}	40	°C/W			

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	SS13M	$I_F = 0.5A, T_J = 25$ °C	V _F	0.45	-	V
		$I_F = 1.0A, T_J = 25^{\circ}C$		0.52	0.55	V
	SS14M	$I_F = 0.5A, T_J = 125^{\circ}C$		0.35	-	V
Converse voltage new diede (1)		$I_F = 1.0A, T_J = 125^{\circ}C$		0.46	0.50	V
Forward voltage per diode (1)		$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.51	-	V
	004014	$I_F = 1.0A, T_J = 25^{\circ}C$		0.64	0.68	V
	SS16M	$I_F = 0.5A, T_J = 125^{\circ}C$		0.46	-	V
		$I_F = 1.0A, T_J = 125^{\circ}C$		0.57	0.60	V
	SS13M SS14M	T _J = 25°C	I _R	5	50	μΑ
		T _J = 125°C		3	10	mA
Reverse current @ rated V _R		T _J = 150°C		5.3	-	mA
per diode (2)		T _J = 25°C	I _R	5	50	μA
	SS16M	T _J = 125°C		3	10	mA
		T _J = 150°C		6	-	mA
Junction capacitance	SS13M SS14M	1 MHz, V _R =4.0V	CJ	50	-	pF
	SS16M	, , ,		40	-	pF

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
ORDERING CODE	PACKAGE	PACKING			
SS13MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS14MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS16MHRSG	Micro SMA	3000 / 7" Plastic reel			
SS13M RSG	Micro SMA	3000 / 7" Plastic reel			
SS14M RSG	Micro SMA	3000 / 7" Plastic reel			
SS16M RSG	Micro SMA	3000 / 7" Plastic reel			

Note: "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve

1.2 AVERAGE FORWARD CURRENT (A) 1 8.0 0.6 0.4 0.2 **RESISTIVE OR** INDUCTIVE LOAD 0 0 25 50 75 100 125 150 LEAD TEMPERATURE (°C)

Fig.2 Typical Junction Capacitance

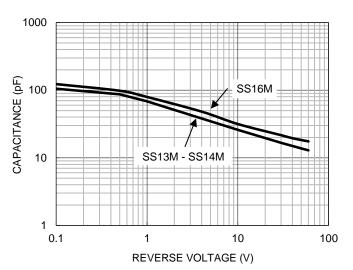
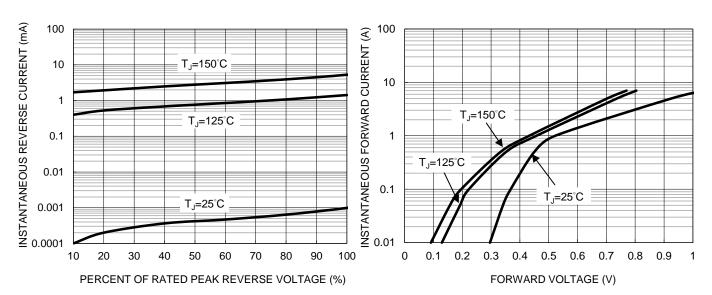


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



3

Version: N1810



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.5 Typical Reverse Characteristics

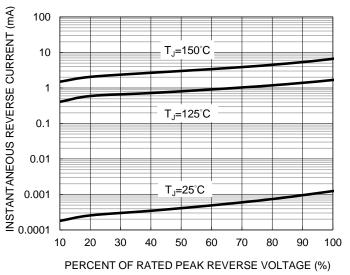


Fig.6 Typical Forward Characteristics

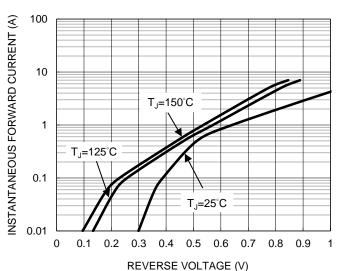


Fig.7 Maximum Forward Surge Current

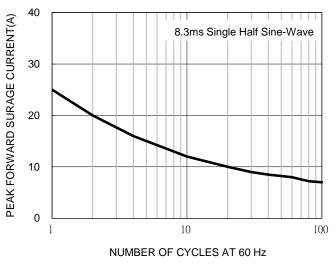
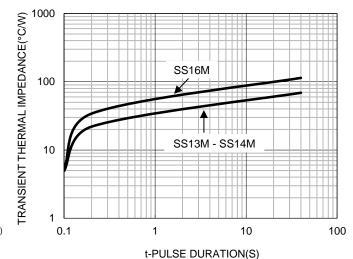


Fig.8 Typical Transient Thermal Impedance

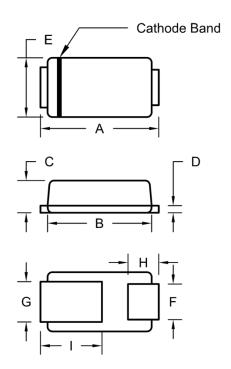


4 Version: N1810



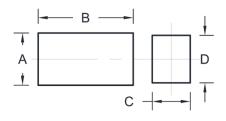
PACKAGE OUTLINE DIMENSIONS

Micro SMA



DIM	Unit	(mm)	Unit (inch)		
DIIVI	Min.	Max.	Min.	Max.	
Α	2.30	2.70	0.091	0.106	
В	2.10	2.30	0.083	0.091	
С	0.63	0.73	0.025	0.029	
D	0.10	0.20	0.004	0.008	
E	1.15	1.35	0.045	0.053	
F	0.65	0.85	0.026	0.034	
G	0.75	0.95	0.030	0.037	
Н	0.55	0.75	0.022	0.030	
I	1.10	1.50	0.043	0.059	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	1.10	0.043
В	2.00	0.079
С	0.80	0.031
D	1.00	0.039

MARKING DIAGRAM



P/N = Marking Code YW = Date Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT
54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP
SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP
SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF
ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
NTE6081